



Thyristor Module

= 2x 1800 V

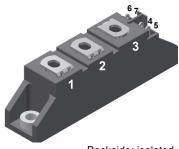
140 A

 V_{T} 1.28 V

Phase leg

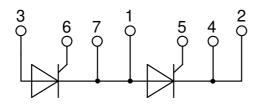
Part number

MCMA140P1800TA



Backside: isolated





Features / Advantages:

- Thyristor for line frequency
- Planar passivated chip
- Long-term stability
- Direct Copper Bonded Al2O3-ceramic

Applications:

- Line rectifying 50/60 Hz
- Softstart AC motor control
- DC Motor control
- Power converter
- AC power control
- Lighting and temperature control

Package: TO-240AA

- Isolation Voltage: 4800 V~
- Industry standard outline
- RoHS compliant
- Soldering pins for PCB mounting
- Base plate: DCB ceramic
- Reduced weight
- Advanced power cycling

Disclaimer Notice

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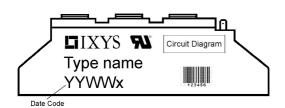


Thyristo				l	Ratings		1 -
Symbol	Definition	Conditions		min.	typ.	max.	Un
V _{RSM/DSM}	max. non-repetitive reverse/forwa	rd blocking voltage	$T_{VJ} = 25^{\circ}C$			1900	
$V_{RRM/DRM}$	max. repetitive reverse/forward bl	<u> </u>	$T_{VJ} = 25^{\circ}C$			1800	
I _{R/D}	reverse current, drain current	$V_{R/D} = 1800 \text{ V}$	$T_{VJ} = 25^{\circ}C$			100	μ
		$V_{R/D} = 1800 \text{ V}$	$T_{VJ} = 140$ °C			10	m
V _T	forward voltage drop	$I_T = 150 A$	$T_{VJ} = 25^{\circ}C$			1.29	,
		$I_T = 300 A$				1.63	,
		$I_{T} = 150 \text{ A}$	T _{vJ} = 125°C			1.28	,
		$I_T = 300 \text{ A}$				1.70	,
I _{TAV}	average forward current	T _C = 85°C	$T_{VJ} = 140$ °C			140	
I _{T(RMS)}	RMS forward current	180° sine				220	
V _{T0}	threshold voltage		T _{vJ} = 140°C			0.85	,
r _T	slope resistance	oss calculation only				2.8	m۵
R _{thJC}	thermal resistance junction to cas	e				0.22	K/V
R _{thCH}	thermal resistance case to heatsii				0.2		K/V
P _{tot}	total power dissipation		T _C = 25°C			520	٧
I _{TSM}	max. forward surge current	t = 10 ms; (50 Hz), sine	$T_{VJ} = 45^{\circ}C$			2.40	k
-15M		t = 8.3 ms; (60 Hz), sine	$V_R = 0 V$			2.59	k/
		t = 0.0 ms; (50 Hz), sine	$T_{VJ} = 140^{\circ}C$			2.04	k,
		t = 8.3 ms; (60 Hz), sine	$V_{R} = 0 V$			2.21	k
l²t	value for fusing	t = 0.5 ms; (50 Hz), sine	$T_{VJ} = 45^{\circ}C$			28.8	kA ²
	value for fushing	t = 8.3 ms; (60 Hz), sine	$V_R = 0 V$			27.9	kA ²
		t = 0.5 ms; (50 Hz), sine t = 10 ms; (50 Hz), sine	$V_{R} = 0 V$ $T_{V,I} = 140 ^{\circ}C$			20.8	kA ²
							į
^	iunation canacitanas	t = 8,3 ms; (60 Hz), sine	$V_R = 0 V$		110	20.2	-
C,	junction capacitance	V _R = 400 V f = 1 MHz	$T_{VJ} = 25^{\circ}C$		119	10	р
P_{GM}	max. gate power dissipation	$t_P = 30 \mu s$	$T_{C} = 140 ^{\circ}C$			10	۷
_		$t_{P} = 300 \mu s$				5	۷
P _{GAV}	average gate power dissipation					0.5	V
(di/dt) _{cr}	critical rate of rise of current		epetitive, $I_T = 450 A$			150	A/μ
		$t_P = 200 \mu s; di_G/dt = 0.45 A/\mu s;$					
			on-repet., $I_T = 150 A$			500	i
(dv/dt) _{cr}	critical rate of rise of voltage	$V = \frac{2}{3} V_{DRM}$	$T_{VJ} = 140$ °C			1000	V/μ
		R _{GK} = ∞; method 1 (linear volta					
V_{GT}	gate trigger voltage	$V_D = 6 V$	$T_{VJ} = 25^{\circ}C$			1.5	١
			$T_{VJ} = -40$ °C			1.6	١
I _{GT}	gate trigger current	$V_D = 6 V$	$T_{VJ} = 25^{\circ}C$			150	m
			$T_{VJ} = -40$ °C			200	m
V _{GD}	gate non-trigger voltage	$V_D = \frac{2}{3} V_{DRM}$	$T_{VJ} = 140^{\circ}C$			0.2	١
I _{GD}	gate non-trigger current					10	m
I _L	latching current	t _p = 10 μs	T _{VJ} = 25°C			200	m
		$I_G = 0.45 \text{A}; di_G/dt = 0.45 \text{A/}\mu s$	3				İ
I _H	holding current	$V_D = 6 \text{ V } R_{GK} = \infty$	T _{vJ} = 25°C			200	m
t _{gd}	gate controlled delay time	$V_D = \frac{1}{2} V_{DRM}$	T _{VJ} = 25°C			2	μ
yu	-	$I_{\rm G} = 0.45 \text{A}; \text{di}_{\rm G}/\text{dt} = 0.45 \text{A}/\mu \text{s}$				_	r
t _q	turn-off time	$V_{\rm R} = 100 \text{ V}; \ I_{\rm T} = 150 \text{A}; \ V = \frac{2}{3}$			185		μ
• q		$di/dt = 10 \text{ A}/\mu \text{s} \text{ dv/dt} = 20 \text{ V}$			100		μ



MCMA140P1800TA

Package	Package TO-240AA			Ratings				
Symbol	Definition	Conditions			min.	typ.	max.	Unit
I _{RMS}	RMS current	per terminal					200	Α
T _{VJ}	virtual junction temperature	е			-40		140	°C
T _{op}	operation temperature				-40		125	°C
T _{stg}	storage temperature				-40		125	°C
Weight						81		g
M _D	mounting torque				2.5		4	Nm
$\mathbf{M}_{_{T}}$	terminal torque				2.5		4	Nm
d _{Spp/App}	and the second s	ace striking distance through air	terminal to terminal	13.0	9.7			mm
d _{Spb/Apb}	creepage distance on sun	ace striking distance through an	terminal to backside	16.0	16.0			mm
V _{ISOL}	isolation voltage	t = 1 second			4800			٧
1002	t = 1 minute		50/60 Hz, RMS; lisoL ≤ 1 mA		4000			٧



Part description

M = Module
C = Thyristor (SCR)
M = Thyristor

A = (up to 1800V) 140 = Current Rating [A] P = Phase leg

1800 = Reverse Voltage [V]

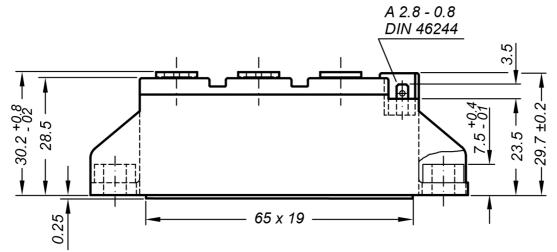
TA = TO-240AA-1B

Ordering	Ordering Number Marking on Product		Delivery Mode	Quantity	Code No.
Standard	MCMA140P1800TA	MCMA140P1800TA	Box	36	512880

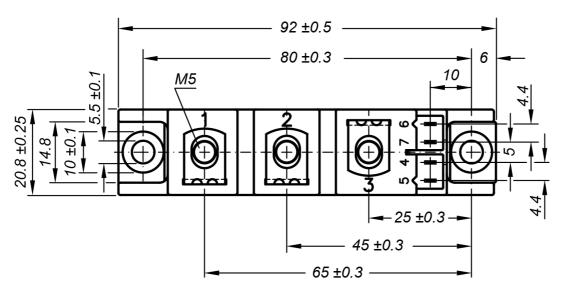
Equiva	alent Circuits for	Simulation	* on die level	$T_{VJ} = 140^{\circ}C$
$I \rightarrow V_0$)— <u>R</u> o	Thyristor		
V _{0 max}	threshold voltage	0.85		V
$R_{0 max}$	slope resistance *	1.6		$m\Omega$



Outlines TO-240AA



General tolerance: DIN ISO 2768 class "c"



Optional accessories for modules

Keyed gate/cathode twin plugs with wire length = 350 mm, gate = white, cathode = red Type ZY 200L (L = Left for pin pair 4/5) Type ZY 200R (R = Right for pin pair 6/7)

UL 758, style 3751

